

CIR-S5DUSE5608G

DDR5 DIMM 5600MHz 8GB

Description

CIR-S5DUSE5608G is a 1G x 64-bit (8GB) DDR5-5600 CL46 SDRAM (Synchronous DRAM), 1Rx16, memory module, based on eight 1G x 16-bit FBGA components. The SPD is programmed to JEDEC standard latency DDR5-5600 timing of 46-45-45 at 1.1V. Each 288-pin DIMM uses gold contact fingers. Power management integrated circuit (PMIC) provides better signal integrity and more stable power. Original DRAM chips and all components are stringently tested for the highest level of compatibility, reliability, and performance.

Specifications

Density	8GB
Pin Count	288pin
Type	Unbuffered
Dimensions	133.35mm x 31.25mm
ECC	Non-ECC
Component Config	1G x 16 bit
Data Rate	5600 MHz
CAS Latency	46
Voltage	1.1V
PCB Layers	8
Operating Temp.(TCASE)	0°C~+85°C
Module Ranks	Single Rank

Features

- JEDEC Standard 288-pin Dual In-Line Memory Module
- VDD = VDDQ = 1.1V (1.067V~1.166V)
- VPP = VDDSPD =1.8V
- Programmable /CAS Latency: 22,26,28,30,32,36,40,42,46,50
- PMIC on DIMM, nominal supply 5V, VIN_Bulk input supply range: 4.25 V to 5.5 V
- On-die, internal, adjustable VREF generation for DQ,CA,CS
- 16n-bit prefetch
- Two independent I/O sub channels
- On-Die ECC
- SPD Hub with Thermal Sensor
- Fly-By topology
- Terminated control, command and address bus
- RoHS Compliant and Halogen free

